

High Voltage, High Current Darlington Transistor Array

The seven NPN Darlington connected transistors in this array are well suited for driving lamps, relays, or printer hammers in a variety of industrial and consumer applications. Their high breakdown voltage and internal suppression diodes insure freedom from problems associated with inductive loads. Peak inrush currents to 600 mA permit them to drive incandescent lamps.

The MCT1413, B with a 2.7 k Ω series input resistor is well suited for systems utilizing a 5.0 V TTL or CMOS Logic.

This MCT–prefixed device is intended to be a possible replacement for the similar device with the MC–prefix. Because the MCT device originates from different source material, there may be subtle differences in typical parameter values or characteristic curves. Due to the diversity of potential applications, Motorola can not assure identical performance in all circuits. Motorola recommends that the customer qualify the MCT–prefixed device in each potential application.

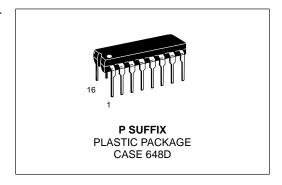
MAXIMUM RATINGS ($T_A = 25^{\circ}C$ and rating apply to any one device in the package unless otherwise noted.)

Rating	Symbol	Value	Unit
Output Voltage	٧o	50	V
Input Voltage	٧ _I	30	V
Collector Current – Continuous	IC	500	mA
Base Current – Continuous	ΙΒ	25	mA
Operating Ambient Temperature Range MCT1413 MCT1413B	T _A	- 20 to + 85 - 40 to + 85	°C
Storage Temperature Range	T _{stg}	- 55 to +150	°C
Junction Temperature	TJ	150	°C
Thermal Resistance – Junction–to–Ambient	θЈА	67	°C/W

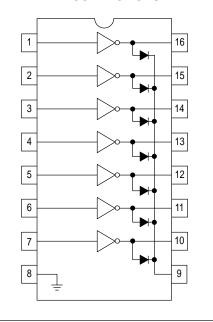
CAUTION: These devices do not have internal ESD protection circuitry and are rated as CLASS 1 devices per the ESD test method in Mil–Std–833D. They should be handled using standard ESD prevention methods to avoid damage to the device.

PERIPHERAL DRIVER ARRAY

SEMICONDUCTOR TECHNICAL DATA



PIN CONNECTIONS



ORDERING INFORMATION

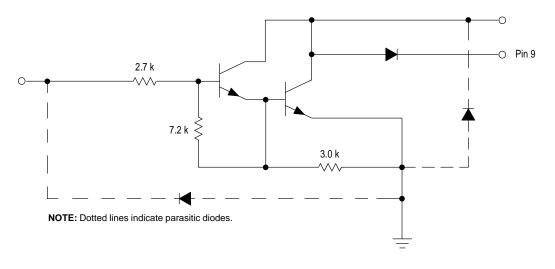
Device	Operating Temperature Range	Package
MCT1413P (ULN2003A)	$T_A = -20^{\circ} \text{ to } +85^{\circ}\text{C}$	Plastic
MCT1413BP	$T_A = -40^{\circ} \text{ to } +85^{\circ}\text{C}$	1 12.01.0

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$, unless otherwise noted.)

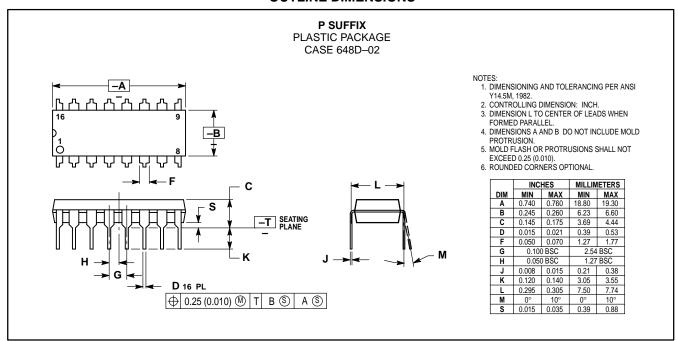
Characteristic		Symbol	Min	Тур	Max	Unit
Output Leakage Current (V _O = 50 V) (V _O = 50 V, T _A = + 85°C) (V _O = 50 V, T _A = -40°C)	MCT1413, B MCT1413, B MCT1413B	ICEX	- - -	- - -	50 100 100	μА
Collector–Emitter Saturation Voltage $ \begin{array}{l} \text{(IC} = 350 \text{ mA, IB} = 500 \mu\text{A}) \\ \text{(IC} = 200 \text{ mA, IB} = 350 \mu\text{A}) \\ \text{(IC} = 100 \text{ mA, IB} = 250 \mu\text{A}) \\ \text{(IC} = 100 \text{ mA, IB} = 2500 \mu\text{A}, \text{TA} = +85^{\circ}\text{C}, -40^{\circ}\text{C}) \\ \text{(IC} = 200 \text{ mA, IB} = 350 \mu\text{A}, \text{TA} = +85^{\circ}\text{C}, -40^{\circ}\text{C}) \\ \text{(IC} = 100 \text{ mA, IB} = 250 \mu\text{A}, \text{TA} = +85^{\circ}\text{C}, -40^{\circ}\text{C}) \\ \end{array} $	MCT1413, B MCT1413, B MCT1413, B MCT1413B MCT1413B MCT1413B	VCE(sat)	- - - - -	1.1 0.95 0.85 - - -	1.6 1.3 1.1 1.75 1.5	V
Input Current – ON Condition (V _{in} = 3.85 V)	MCT1413, B	l _{in}	-	0.93	1.35	mA
Output Voltage $-$ ON Condition ($V_{in} = 2.4 \text{ V}, \text{ IC} = 200 \text{ mA}$) ($V_{in} = 2.7 \text{ V}, \text{ IC} = 250 \text{ mA}$) ($V_{in} = 3.0 \text{ V}, \text{ IC} = 300 \text{ mA}$) ($V_{in} = 2.7 \text{ V}, \text{ IC} = 250 \text{ mA}, \text{ TA} = +85^{\circ}\text{C}, -40^{\circ}\text{C}$) ($V_{in} = 3.0 \text{ V}, \text{ IC} = 300 \text{ mA}, \text{ TA} = +85^{\circ}\text{C}, -40^{\circ}\text{C}$)	MCT1413, B MCT1413, B MCT1413, B MCT1413B MCT1413B	V _{out}			2.0 2.0 2.0 2.0 2.0	٧
Output Current – OFF Condition ($I_{in} = 50 \mu A$, $V_{out} = 5.0 V$) ($I_{in} = 50 \mu A$, $V_{out} = 5.0 V$, $T_{A} = +85^{\circ}C$) ($I_{in} = 50 \mu A$, $V_{out} = 5.0 V$, $T_{A} = -40^{\circ}C$)	MCT1413, B MCT1413, B MCT1413B	l _{out}	- - -	- - -	100 500 500	μА
Clamp Diode Leakage Current (V _R = 50 V) (V _R = 50 V, T _A = +85°C) (V _R = 50 V, T _A = -40°C)	MCT1413, B MCT1413, B MCT1413B	IR	- - -	- - -	50 100 100	μА
Clamp Diode Forward Voltage (I _F = 350 mA) (I _F = 350 mA, T _A = +85°C, -40°C)	MCT1413, B MCT1413B	VF	_ _	1.5 -	2.0 2.0	V

Figure 1. Representative Schematic Diagram (1/7 MCT1413, B)



This device contains 14 active transistors.

OUTLINE DIMENSIONS



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MCT1413B/D